NSN 5961-01-058-7785

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View Online at https://aerobasegroup.com/nsn/5961-01-058-7785 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc and 40.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.2 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 80063-sm-a-726664 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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